

74HC4852-Q100; 74HCT4852-Q100

Dual 4-channel analog multiplexer/demultiplexer with
injection-current effect control

Rev. 2 — 28 April 2020

Product data sheet

1. General description

The 74HC4852-Q100; 74HCT4852-Q100 are dual single-pole quad-throw analog switches (SP4T) suitable for use in analog or digital 4:1 multiplexer/demultiplexer applications. Each switch features four independent inputs/outputs (nY0, nY1, nY2 and nY3) and a common input/output (nZ). A digital enable input (E) and two digital select inputs (S0 & S1) are common to both switches. When \bar{E} is HIGH, the switches are turned off. The device features injection-current effect control. This allows signals at disabled analog input channels to exceed the supply voltage without affecting the signal of the enabled analog channel, eliminating the need for external diode/resistor networks typically used to keep the analog channel signals within the supply-voltage range. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Injection-current cross coupling < 1 mV/mA
- Wide supply voltage range from 2.0 V to 6.0 V for 74HC4852-Q100
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Latch-up performance exceeds 100 mA per JESD 78 Class II level A
- Low ON-state resistance:
 - 400 Ω (typical) at $V_{CC} = 2.0$ V
 - 215 Ω (typical) at $V_{CC} = 3.0$ V
 - 120 Ω (typical) at $V_{CC} = 3.3$ V
 - 76 Ω (typical) at $V_{CC} = 4.5$ V
 - 59 Ω (typical) at $V_{CC} = 6.0$ V
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating
- Automotive application

4. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|------------------|-------------------|----------|--|----------|
| | Temperature range | Name | Description | |
| 74HC4852D-Q100 | -40 °C to +125 °C | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |
| 74HCT4852D-Q100 | | | | |
| 74HC4852PW-Q100 | -40 °C to +125 °C | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 |
| 74HCT4852PW-Q100 | | | | |
| 74HC4852BQ-Q100 | -40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | SOT763-1 |
| 74HCT4852BQ-Q100 | | | | |

5. Functional diagram

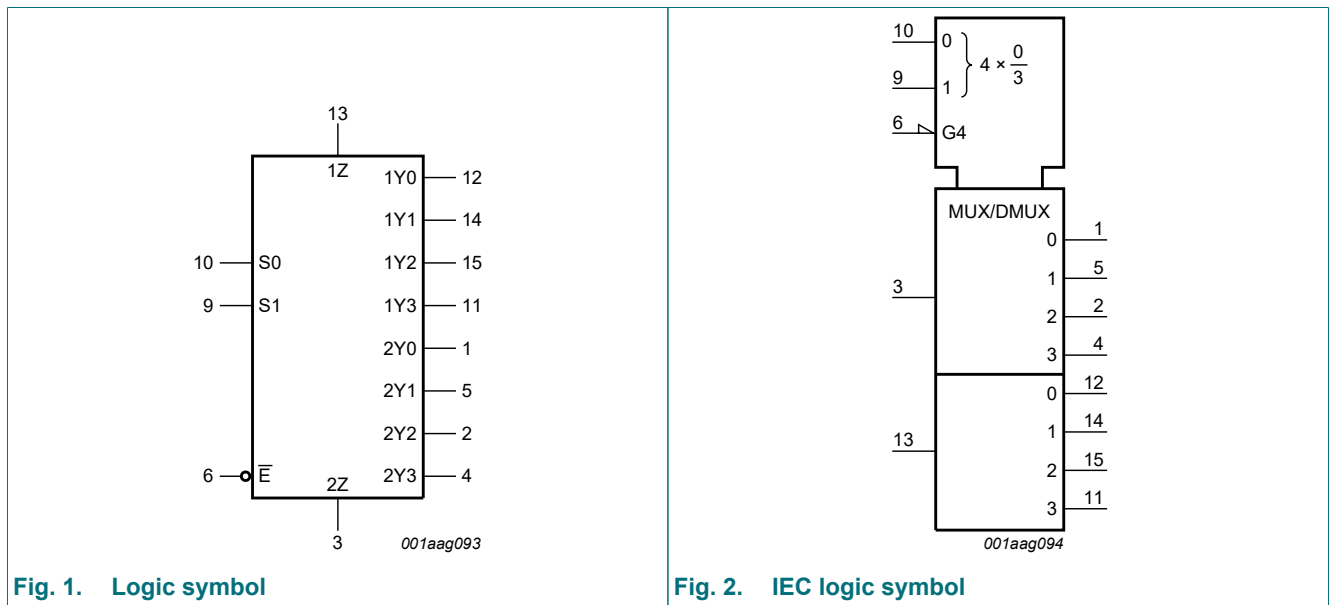


Fig. 1. Logic symbol

Fig. 2. IEC logic symbol



Fig. 3. Functional diagram

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|-----|---------------------------|
| 2Y0 | 1 | independent input/output |
| 2Y2 | 2 | independent input/output |
| 2Z | 3 | common input/output |
| 2Y3 | 4 | independent input/output |
| 2Y1 | 5 | independent input/output |
| \bar{E} | 6 | enable input (active LOW) |
| n.c. | 7 | not connected |
| GND | 8 | ground (0 V) |
| S1 | 9 | select input |
| S0 | 10 | select input |
| 1Y3 | 11 | independent input/output |
| 1Y0 | 12 | independent input/output |
| 1Z | 13 | common input/output |
| 1Y1 | 14 | independent input/output |
| 1Y2 | 15 | independent input/output |
| V _{CC} | 16 | supply voltage |

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

| Input | | | Channel ON |
|-------|----|----|------------|
| E | S1 | S0 | |
| L | L | L | nY0 to nZ |
| L | L | H | nY1 to nZ |
| L | H | L | nY2 to nZ |
| L | H | H | nY3 to nZ |
| H | X | X | - |

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|--|------|----------------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| V_I | input voltage | [1] | -0.5 | $V_{CC} + 0.5$ | V |
| V_{SW} | switch voltage | [2] | -0.5 | $V_{CC} + 0.5$ | V |
| I_{IK} | input clamping current | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V | - | ± 20 | mA |
| I_{SK} | switch clamping current | $V_{SW} < -0.5$ V or $V_{SW} > V_{CC} + 0.5$ V | - | ± 20 | mA |
| I_{SW} | switch current | $V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V | - | ± 25 | mA |
| I_{CC} | supply current | | - | 50 | mA |
| I_{GND} | ground current | | -50 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C [3] | - | 500 | mW |

- [1] The minimum and maximum input voltage rating may be exceeded if the input clamping current rating is observed.
 [2] The minimum and maximum switch voltage rating may be exceeded if the switch clamping current rating is observed.
 [3] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.
 For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.
 For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | 74HC4852-Q100 | | | 74HCT4852-Q100 | | | Unit |
|---------------------|-------------------------------------|-------------------------|---------------|-----|----------|----------------|-----|----------|------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| V_{CC} | supply voltage | | 2.0 | - | 6.0 | 4.5 | 5.0 | 5.5 | V |
| V_I | input voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| V_{SW} | switch voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | - | +125 | -40 | - | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 2.0\text{ V}$ | - | 6.0 | 1 000 | - | - | - | ns/V |
| | | $V_{CC} = 3.0\text{ V}$ | - | 6.0 | 800 | - | - | - | ns/V |
| | | $V_{CC} = 3.3\text{ V}$ | - | 6.0 | 800 | - | - | - | ns/V |
| | | $V_{CC} = 4.5\text{ V}$ | - | 6.0 | 500 | - | 6.0 | 500 | ns/V |
| | | $V_{CC} = 6.0\text{ V}$ | - | 6.0 | 400 | - | - | - | ns/V |

10. Static characteristics

Table 6. R_{ON} resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 8.

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------------------|---|--|-------|-----|-----|------------------|-----|-------------------|-----|----------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HC4852-Q100 | | | | | | | | | | |
| $R_{ON(peak)}$ | ON resistance (peak) | $V_I = V_{CC}$ to GND; $\bar{E} = V_{IL}$ | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}; I_{SW} = 2\text{ mA}$ | - | 400 | 650 | - | 670 | - | 700 | Ω |
| | | $V_{CC} = 3.0\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 215 | 330 | - | 360 | - | 380 | Ω |
| | | $V_{CC} = 3.3\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 120 | 270 | - | 305 | - | 345 | Ω |
| | | $V_{CC} = 4.5\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 76 | 210 | - | 240 | - | 270 | Ω |
| | | $V_{CC} = 6.0\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 59 | 195 | - | 220 | - | 250 | Ω |
| ΔR_{ON} | ON resistance mismatch between channels | $V_I = 0.5 \times V_{CC}; \bar{E} = V_{IL}$ | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}; I_{SW} = 2\text{ mA}$ | - | 4 | 10 | - | 15 | - | 20 | Ω |
| | | $V_{CC} = 3.0\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 2 | 8 | - | 12 | - | 16 | Ω |
| | | $V_{CC} = 3.3\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 2 | 8 | - | 12 | - | 16 | Ω |
| | | $V_{CC} = 4.5\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 2 | 8 | - | 12 | - | 16 | Ω |
| | | $V_{CC} = 6.0\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 3 | 9 | - | 13 | - | 18 | Ω |
| 74HCT4852-Q100 | | | | | | | | | | |
| $R_{ON(peak)}$ | ON resistance (peak) | $V_I = V_{CC}$ to GND; $\bar{E} = V_{IL}$ | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 76 | 210 | - | 240 | - | 270 | Ω |
| ΔR_{ON} | ON resistance mismatch between channels | $V_I = 0.5 \times V_{CC}; \bar{E} = V_{IL}$ | | | | | | | | |
| | | $V_{CC} = 4.5\text{ V}; I_{SW} \leq 2\text{ mA}$ | - | 2 | 8 | - | 12 | - | 16 | Ω |

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

Table 7. Injection current coupling

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 9.

| Symbol | Parameter | Conditions | 74HC4852-Q100 | | | 74HCT4852-Q100 | | | Unit | |
|--|--------------------------|---|---------------|--------|------|----------------|--------|-----|------|--|
| | | | Min | Typ[1] | Max | Min | Typ[1] | Max | | |
| T_{amb} = -40 °C to +125 °C | | | | | | | | | | |
| ΔV_O | output voltage variation | $ I_{SW} \leq 1 \text{ mA}; R_S \leq 3.9 \text{ k}\Omega$ [2][3] | | | | | | | | |
| | | $V_{CC} = 3.3 \text{ V}$ | - | 0.05 | 1 | - | - | - | mV | |
| | | $V_{CC} = 5.0 \text{ V}$ | - | 0.03 | 1 | - | 0.03 | 1 | mV | |
| | | $ I_{SW} \leq 10 \text{ mA}; R_S \leq 3.9 \text{ k}\Omega$ | | | | | | | | |
| | | $V_{CC} = 3.3 \text{ V}$ | - | 0.55 | 5 | - | - | - | mV | |
| | | $V_{CC} = 5.0 \text{ V}$ | - | 0.27 | 5 | - | 0.27 | 5 | mV | |
| | | $ I_{SW} \leq 1 \text{ mA}; R_S \leq 20 \text{ k}\Omega$ | | | | | | | | |
| | | $V_{CC} = 3.3 \text{ V}$ | - | 0.04 | 2 | - | - | - | mV | |
| | | $V_{CC} = 5.0 \text{ V}$ | - | 0.03 | 2 | - | 0.03 | 2 | mV | |
| | | $ I_{SW} \leq 10 \text{ mA}; R_S \leq 20 \text{ k}\Omega$ | | | | | | | | |
| | | $V_{CC} = 3.3 \text{ V}$ | - | 0.56 | 20 | - | - | - | mV | |
| $V_{CC} = 5.0 \text{ V}$ | - | 0.48 | 20 | - | 0.48 | 20 | mV | | | |

[1] Typical values are measured at T_{amb} = 25 °C.[2] ΔV_O here is the maximum variation of output voltage of an enabled analog channel when current is injected into any disabled channel.[3] I_{SW} = total current injected into all disabled channels.

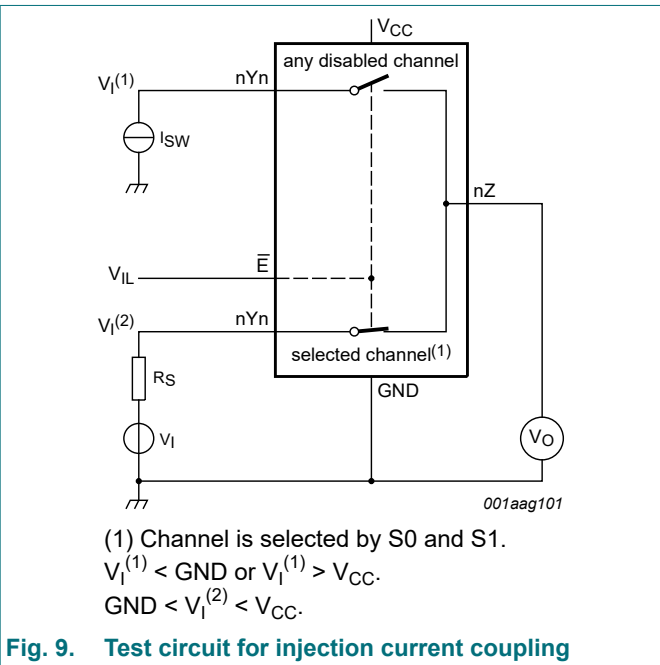
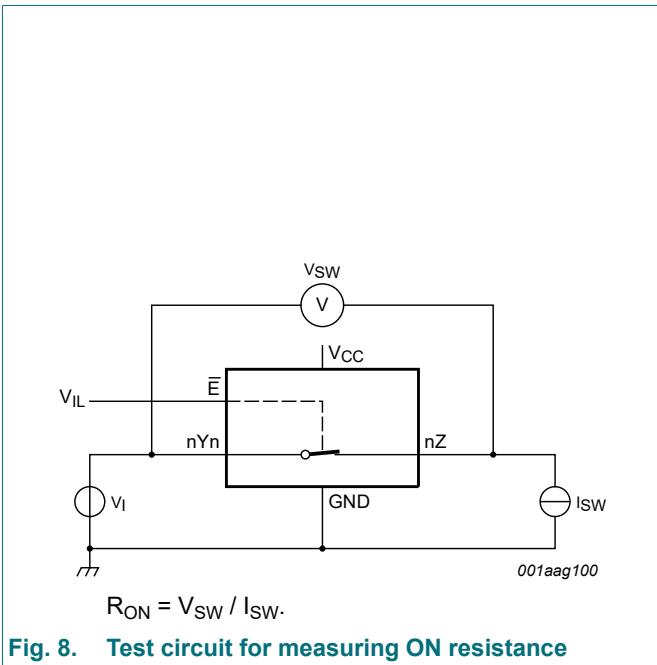
Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|----------------------|---------------------------|--|-------|-----|------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HC4852-Q100 | | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | control inputs | | | | | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| | | $V_{CC} = 3.0 \text{ V}$ | 2.1 | - | - | 2.1 | - | 2.1 | - | V |
| | | $V_{CC} = 3.3 \text{ V}$ | 2.3 | - | - | 2.3 | - | 2.3 | - | V |
| | | $V_{CC} = 4.5 \text{ V}$ | 3.15 | - | - | 3.15 | - | 3.15 | - | V |
| | | $V_{CC} = 6.0 \text{ V}$ | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| V _{IL} | LOW-level input voltage | control inputs | | | | | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | | $V_{CC} = 3.0 \text{ V}$ | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | $V_{CC} = 3.3 \text{ V}$ | - | - | 1.0 | - | 1.0 | - | 1.0 | V |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 1.35 | - | 1.35 | - | 1.35 | V |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| I _I | input leakage current | control inputs; V _I = GND or V _{CC} | | | | | | | | |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | ±0.1 | - | ±0.1 | - | ±1.0 | µA |
| I _{S(OFF)} | OFF-state leakage current | $\bar{E} = V_{IH}; V_I = \text{GND or } V_{CC}; V_O = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V};$ see Fig. 6 | | | | | | | | |
| | | nYn; per channel | - | - | ±0.1 | - | ±0.5 | - | ±1.0 | µA |
| | | nZ; all channels | - | - | ±0.2 | - | ±2.0 | - | ±4.0 | µA |

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------------------|---------------------------|--|-------|-----|-----------|------------------|-----------|-------------------|-----------|---------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| $I_{S(ON)}$ | ON-state leakage current | $\bar{E} = V_{IL}$; $V_I = GND$ or V_{CC} ; $V_O = V_{CC}$ or GND ; $V_{CC} = 6.0 V$; see Fig. 7 | - | - | ± 0.1 | - | ± 0.5 | - | ± 1.0 | μA |
| I_{CC} | supply current | $V_I = GND$ or V_{CC} $V_{CC} = 6.0 V$ | - | - | 2.0 | - | 5.0 | - | 20.0 | μA |
| C_I | input capacitance | S0, S1, S2 and \bar{E} | - | 2 | 10 | - | 10 | - | 10 | pF |
| C_{sw} | switch capacitance | nZ; OFF-state | - | 15 | 40 | - | 40 | - | 40 | pF |
| | | nYn; OFF-state | - | 3 | 15 | - | 15 | - | 15 | pF |
| 74HCT4852-Q100 | | | | | | | | | | |
| V_{IH} | HIGH-level input voltage | control inputs | | | | | | | | |
| | | $V_{CC} = 4.5 V$ to $5.5 V$ | 2.0 | - | - | 2.0 | - | 2.0 | - | V |
| V_{IL} | LOW-level input voltage | control inputs | | | | | | | | |
| | | $V_{CC} = 4.5 V$ to $5.5 V$ | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| I_I | input leakage current | control inputs; $V_I = GND$ or V_{CC} | | | | | | | | |
| | | $V_{CC} = 5.5 V$ | - | - | ± 0.1 | - | ± 0.1 | - | ± 1.0 | μA |
| $I_{S(OFF)}$ | OFF-state leakage current | $\bar{E} = V_{IH}$; $V_I = GND$ or V_{CC} ; $V_O = V_{CC}$ or GND ; $V_{CC} = 5.5 V$; see Fig. 6 | | | | | | | | |
| | | per channel | - | - | ± 0.1 | - | ± 0.5 | - | ± 1.0 | μA |
| | | all channels | - | - | ± 0.2 | - | ± 2.0 | - | ± 4.0 | μA |
| $I_{S(ON)}$ | ON-state leakage current | $\bar{E} = V_{IL}$; $V_I = GND$ or V_{CC} ; $V_O = V_{CC}$ or GND ; $V_{CC} = 5.5 V$; see Fig. 7 | - | - | ± 0.1 | - | ± 0.5 | - | ± 1.0 | μA |
| I_{CC} | supply current | $V_I = GND$ or V_{CC} | | | | | | | | |
| | | $V_{CC} = 5.5 V$ | - | - | 2.0 | - | 5.0 | - | 20.0 | μA |
| ΔI_{CC} | additional supply current | control inputs; $V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND ; $V_{CC} = 4.5 V$ to $5.5 V$; $I_O = 0 A$ | - | - | 300 | - | 370 | - | 370 | μA |
| C_I | input capacitance | S0, S1, S2 and \bar{E} | - | 2 | 10 | - | 10 | - | 10 | pF |
| C_{sw} | switch capacitance | nZ; OFF-state | - | 9 | 40 | - | 40 | - | 40 | pF |
| | | nYn; OFF-state | - | 3 | 15 | - | 15 | - | 15 | pF |



11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 14.

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-------------------------|-------------------------------|---------------------------------------|-------|------|------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HC4852-Q100 | | | | | | | | | | |
| t_{pd} | propagation delay | nZ, nYn to nYn, nZ; see Fig. 10 [1] | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | 2.2 | 9.3 | 33 | 2.2 | 34 | 2.2 | 35 | ns |
| | | $V_{CC} = 3.0\text{ V}$ | 2.2 | 4.9 | 16.5 | 1.9 | 18 | 1.9 | 19.5 | ns |
| | | $V_{CC} = 3.3\text{ V}$ | 2.0 | 4.4 | 15.0 | 1.6 | 16.5 | 1.6 | 18.5 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | 1.6 | 3.2 | 11.6 | 1.1 | 12.5 | 1.1 | 13.5 | ns |
| | | $V_{CC} = 6.0\text{ V}$ | 1.5 | 2.5 | 10.2 | 0.9 | 11 | 0.9 | 12 | ns |
| | | Sn to nZ, nYn; see Fig. 11 [1] | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | 7.7 | 16.8 | 38 | 6.3 | 40 | 6.3 | 42 | ns |
| | | $V_{CC} = 3.0\text{ V}$ | 4.9 | 8.8 | 20 | 3.9 | 21.5 | 3.9 | 23 | ns |
| | | $V_{CC} = 3.3\text{ V}$ | 4.4 | 7.9 | 17.5 | 3.4 | 19 | 3.4 | 22 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | 3.2 | 5.8 | 14 | 2.3 | 15 | 2.3 | 17 | ns |
| $V_{CC} = 6.0\text{ V}$ | 2.4 | 4.8 | 12.6 | 1.6 | 14.5 | 1.6 | 16.5 | ns | | |
| t_{en} | enable time | \bar{E} to nZ, nYn; see Fig. 12 [2] | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | 10.5 | 20.5 | 47.5 | 8.5 | 52.5 | 8.5 | 57.5 | ns |
| | | $V_{CC} = 3.0\text{ V}$ | 6.2 | 10.6 | 45 | 5.2 | 50 | 5.2 | 55 | ns |
| | | $V_{CC} = 3.3\text{ V}$ | 5.6 | 9.4 | 42.5 | 4.6 | 47.5 | 4.6 | 52.5 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | 4.2 | 6.9 | 40 | 3 | 45 | 3 | 50 | ns |
| | | $V_{CC} = 6.0\text{ V}$ | 3.2 | 5.6 | 39 | 2.2 | 40 | 2.2 | 40 | ns |
| t_{dis} | disable time | \bar{E} to nZ, nYn; see Fig. 12 [3] | | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | 39.5 | 75.4 | 100 | 39.3 | 105 | 39 | 115 | ns |
| | | $V_{CC} = 3.0\text{ V}$ | 35.2 | 69.5 | 90 | 35.5 | 100 | 35 | 110 | ns |
| | | $V_{CC} = 3.3\text{ V}$ | 34.6 | 68.1 | 85 | 34.6 | 95 | 34.5 | 105 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | 28.5 | 63 | 80 | 28.2 | 90 | 28 | 100 | ns |
| | | $V_{CC} = 6.0\text{ V}$ | 14.4 | 57.9 | 78 | 13.5 | 80 | 13.0 | 80 | ns |
| C_{PD} | power dissipation capacitance | per channel; see Fig. 13 [4] | | | | | | | | |
| | | $V_{CC} = 3.3\text{ V}$ | - | 42 | - | - | - | - | - | pF |
| | | $V_{CC} = 5.0\text{ V}$ | - | 47 | - | - | - | - | - | pF |

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------------------|-------------------------------|---------------------------------------|-------|------|------|------------------|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HCT4852-Q100 | | | | | | | | | | |
| t _{pd} | propagation delay | nZ, nYn to nYn, nZ; see Fig. 10 [1] | | | | | | | | |
| | | V _{CC} = 4.5 V | 1.6 | 3.5 | 11.5 | 1.1 | 12.5 | 1.1 | 13.5 | ns |
| | | Sn to nZ, nYn; see Fig. 11 [1] | | | | | | | | |
| | | V _{CC} = 4.5 V | 3.2 | 7.6 | 13 | 2.3 | 15 | 1.6 | 17 | ns |
| t _{en} | enable time | \bar{E} to nZ, nYn; see Fig. 12 [2] | | | | | | | | |
| | | V _{CC} = 4.5 V | 4.2 | 8.3 | 25 | 3.0 | 30 | 3.0 | 35 | ns |
| t _{dis} | disable time | \bar{E} to nZ, nYn; see Fig. 12 [3] | | | | | | | | |
| | | V _{CC} = 4.5 V | 28.5 | 61.8 | 80 | 28.2 | 90 | 28.0 | 100 | ns |
| C _{PD} | power dissipation capacitance | per channel; see Fig. 13 [4] | | | | | | | | |
| | | V _{CC} = 5.0 V | - | 47 | - | - | - | - | - | pF |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL}.
- [2] t_{en} is the same as t_{PZH} and t_{PZL}.
- [3] t_{dis} is the same as t_{PLZ} and t_{PHZ}.
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 $\sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;
 C_L = output load capacitance in pF;
 C_{sw} = switch capacitance in pF;
 V_{CC} = supply voltage in V.

11.1. Waveforms



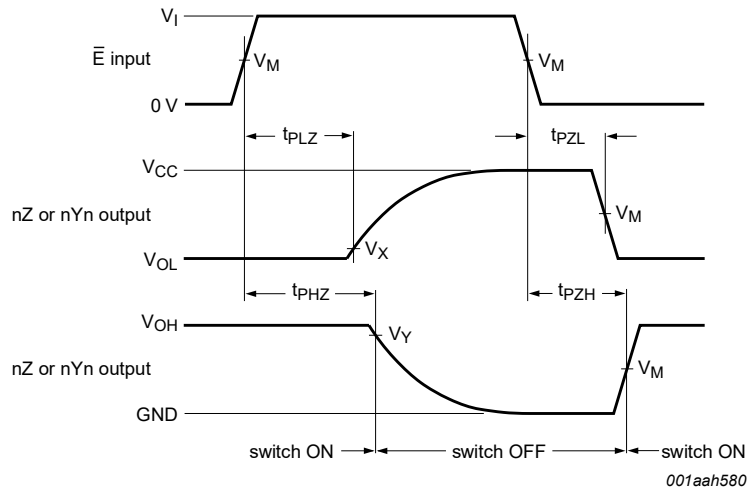
Fig. 10. Input (nZ, nYn) to output (nYn, nZ) propagation delays



Measurement points are given in Table 10.

Fig. 11. Input (Sn) to output (nYn, nZ) propagation delays

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control



Measurement points are shown in [Table 10](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 12. Enable and disable times

Table 10. Measurement points

| Type | Input | | Output | | |
|----------------|-------------|----------|-------------|---------------------------------|-------------|
| | V_M | V_I | V_M | V_X | V_Y |
| 74HC4852-Q100 | $0.5V_{CC}$ | V_{CC} | $0.5V_{CC}$ | $V_{OL} + 0.1(V_{CC} - V_{OL})$ | $0.9V_{OH}$ |
| 74HCT4852-Q100 | 1.3 V | 3.0 V | $0.5V_{CC}$ | $V_{OL} + 0.1(V_{CC} - V_{OL})$ | $0.9V_{OH}$ |

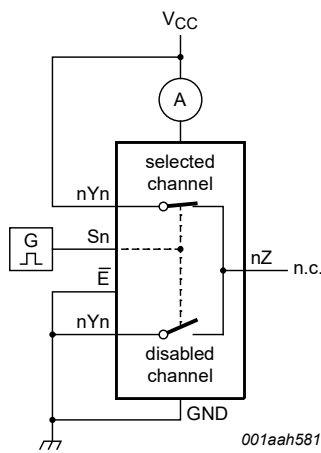
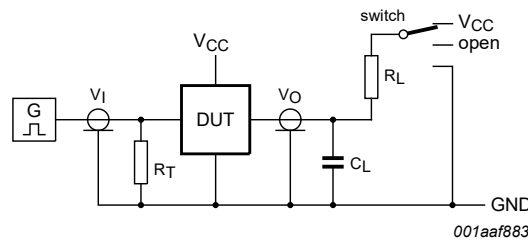


Fig. 13. Test circuit for measuring power dissipation capacitance

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control



a. Input pulse definition



Definitions for test circuit:

R_L = load resistance.

C_L = load capacitance including jig and probe capacitance.

R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

b. Test circuit

Test data is given in [Table 11](#).

Fig. 14. Input pulse definition and test circuit

Table 11. Test data

| Test | Input | | | Output | | S1 position |
|--------------------|---------------------------|-----------------------------|------------|------------------------------|---------------|-------------|
| | Control E, S _n | Switch nY _n (nZ) | t_r, t_f | Switch nZ (nY _n) | | |
| | V_I [1] | V_I | | C_L | R_L | |
| t_{PHL}, t_{PLH} | V_{CC} | V_{CC} | 6 ns | 50 pF | - | open |
| t_{PHZ}, t_{PZH} | V_{CC} | V_{CC} | 6 ns | 50 pF | 10 k Ω | GND |
| t_{PLZ}, t_{PZL} | V_{CC} | V_{CC} | 6 ns | 50 pF | 10 k Ω | V_{CC} |
| C_{PD} | V_{CC} | V_{CC} | 6 ns | 0 pF | - | open |

[1] For 74HCT4852-Q100: input voltage $V_I = 3.0$ V.

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Fig. 15. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Fig. 16. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm

SOT763-1



Fig. 17. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MIL | Military |
| MM | Machine Model |

14. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------------|--|--------------------|---------------|-------------------|
| 74HC_HCT4852_Q100 v.4 | 20200428 | Product data sheet | - | 74HC4852_Q100 v.1 |
| Modifications: | <ul style="list-style-type: none"> • General description: updated. • Features updated. • Table 4: Derating values for P_{tot} total power dissipation have been updated. | | | |
| 74HC4852_Q100 v.1 | 20120712 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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